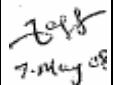
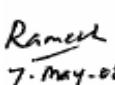
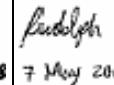


LS100

RELIABILITY DATA

DWG. No PA577-57-01		
APPD	CHK	DWG
 7-May-08	 Rameel 7-May-08	 Rudolph 7 May 2008

I N D E X

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※ The above data is typical value. As all units have nearly the same characteristics, the data to be considered as ability value.

1. Calculated values for MTBF

MODEL : LS100-5

1. Calculating Method

Calculated based on part count reliability projection of JEITA (RCR-9102A).

Individual failure rates λ_G is given to each part and MTBF is calculated by the count of each part.

Formula :

$$\text{MTBF} = \frac{1}{\lambda_{\text{equip}}} = \frac{1}{n \sum_{i=1}^n N_i (\lambda_G \pi_Q)_i} \times 10^6 \text{ (HOURS)}$$

where :

λ_{equip} = Total Equipment Failure Rate (Failure / 106 Hours)

λ_G = Generic Failure Rate For The ith Generic Part (Failure / 106 Hours)

N_i = Quantity of ith Generic Part

n = Number of Different Generic Part Categories

π_Q = Generic Quality Factor for the ith Generic Part ($\pi_Q = 1$)

2. MTBF Values

G_F : (GROUND, FIXED)

MTBF = 545,375 (Hours)

2. Component derating

MODEL : LS100-5

(1) Calculating method

(a) Measuring Conditions

Input	:	115 , 230VAC	• Ambient temperature	:	45°C
Output	:	5V 16A(100%)	• Mounting method	:	Mounting A

(b) Semiconductors

Compared with maximum junction temperature and actual one which is calculated based on case temperature, power dissipation and thermal impedance.

(c) IC, Resistors, Capacitors, etc.

Ambient temperature, operating condition, power dissipation and so on are within derating criteria.

(d) Calculating Method of Thermal Impedance

$$\theta_{j-c} = \frac{T_{j(max)} - T_c}{P_{c(max)}} \quad \theta_{j-a} = \frac{T_{j(max)} - T_a}{P_{c(max)}} \quad \theta_{j-l} = \frac{T_{j(max)} - T_l}{P_{c(max)}}$$

T_c : Case temperature at start point of derating ; 25°C in general

T_a : Ambient temperature at start point of derating ; 25°C in general

T_j : Lead temperature at start point of derating ; 25°C in general

$P_{c(max)}$: Maximum collector(channel) dissipation
 $(P_{ch(max)})$

$T_{j(max)}$: Maximum junction(channel) temperature
 $(T_{ch(max)})$

(θ_{j-c}) : Thermal impedance between junction(channel) and case
 (θ_{ch-c})

θ_{j-a} : Thermal impedance between junction and air

θ_{j-l} : Thermal impedance between junction and lead

(2) Component Derating List

Location No.	Vin = 115VAC	Load = 100%	Ta = 45°C
Q2 STP10NK80Z ST MICROELECTRONICS	Tchmax = 150°C, $\theta_{j-c} = 0.78^\circ\text{C}/\text{W}$, Pch = 3.91W, $\Delta T_c = 59.2^\circ\text{C}$, $T_c = 104.2^\circ\text{C}$ $T_c = T_c + ((\theta_{j-c}) \times Pch) = 107.25^\circ\text{C}$ D.F. = 71.50%	Pch(max) = 160W	
D8 STPS30H60CW ST MICROELECTRONICS	Tjmax = 175°C, $\theta_{j-c} = 0.8^\circ\text{C}/\text{W}$, Pd = 5.2W, $\Delta T_c = 65.2^\circ\text{C}$, $T_c = 110.2^\circ\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times Pd) = 114.36^\circ\text{C}$ D.F. = 65.35%		
D9 STPS30H60CW ST MICROELECTRONICS	Tjmax = 175°C, $\theta_{j-c} = 0.8^\circ\text{C}/\text{W}$, Pd = 5.2W, $\Delta T_c = 65.2^\circ\text{C}$, $T_c = 110.2^\circ\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times Pd) = 114.36^\circ\text{C}$ D.F. = 65.35%		
D1 RS405M RECTRON	Tjmax = 150°C, $\theta_{j-c} = 6.0^\circ\text{C}/\text{W}$ Pd = 2.94W, $\Delta T_c = 61^\circ\text{C}$ $T_c = 106^\circ\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times Pd) = 123.64^\circ\text{C}$ D.F. = 82.43%		
D2 HER208 RECTRON	Tjmax = 150°C, $\theta_{j-c} = 10^\circ\text{C}/\text{W}$ Pd = 0.4W, $\Delta T_c = 81.1^\circ\text{C}$ $T_c = 126.1^\circ\text{C}$ $T_j = T_a + ((\theta_{j-c}) \times Pd) = 130.1^\circ\text{C}$ D.F. = 86.73%		
D4 CRS04 TOSHIBA	Tjmax = 150°C, $\theta_{j-l} = 20^\circ\text{C}/\text{W}$ Pd = 2.5mW, $\Delta T_l = 51.7^\circ\text{C}$ $T_l = 96.7^\circ\text{C}$ $T_j = T_l + ((\theta_{j-l}) \times Pd) = 96.75^\circ\text{C}$ D.F. = 64.50%		
D5 CRS04 TOSHIBA	Tjmax = 150°C, $\theta_{j-l} = 20^\circ\text{C}/\text{W}$ Pd = 5mW, $\Delta T_l = 42.2^\circ\text{C}$ $T_l = 87.2^\circ\text{C}$ $T_j = T_l + ((\theta_{j-l}) \times Pd) = 87.3^\circ\text{C}$ D.F. = 58.20%		
D6 CRF02 TOSHIBA	Tjmax = 150°C, $\theta_{j-l} = 20^\circ\text{C}/\text{W}$ Pd = 39.1mW, $\Delta T_l = 75.5^\circ\text{C}$ $T_c = 120.5^\circ\text{C}$ $T_j = T_a + ((\theta_{j-l}) \times Pd) = 121.28^\circ\text{C}$ D.F. = 80.85%		
D7 CRH01 TOSHIBA	Tjmax = 150°C, $\theta_{j-l} = 20^\circ\text{C}/\text{W}$ Pd = 4.1mW, $\Delta T_l = 77.8^\circ\text{C}$ $T_l = 122.8^\circ\text{C}$ $T_j = T_l + ((\theta_{j-l}) \times Pd) = 122.88^\circ\text{C}$ D.F. = 81.92%		

Location No.	Vin = 115VAC Tjmax = 125°C, $\theta_{j-c} = 150^\circ\text{C}/\text{W}$, $P_c = 3.11\text{mW}$, $\Delta T_c = 45.4^\circ\text{C}$, $T_j = T_c + ((\theta_{j-c}) \times P_c) = 90.87^\circ\text{C}$ D.F. = 72.70%	Load = 100% $P_c(\text{max}) = 0.15\text{W}$ $T_c = 90.4^\circ\text{C}$
PC1 PS2561BL1-1-A(D) (TRANSISTOR) NEC	Tjmax = 125°C, $\theta_{j-c} = 150^\circ\text{C}/\text{W}$, $P_c = 2.34\text{mW}$, $\Delta T_c = 45.4^\circ\text{C}$, $T_j = T_c + ((\theta_{j-c}) \times P_c) = 90.75^\circ\text{C}$ D.F. = 72.60%	$P_c(\text{max}) = 0.15\text{W}$ $T_c = 90.4^\circ\text{C}$
PC2 PS2561BL1-1-A(D) (TRANSISTOR) NEC	Tjmax = 125°C, $\theta_{j-c} = 150^\circ\text{C}/\text{W}$, $P_c = 0.0\text{W}$, $\Delta T_c = 47.5^\circ\text{C}$, $T_j = T_c + ((\theta_{j-c}) \times P_c) = 92.5^\circ\text{C}$ D.F. = 74.00%	$P_c(\text{max}) = 0.15\text{W}$ $T_c = 92.5^\circ\text{C}$
PC2 PS2561BL1-1-A(D) (LED) NEC	Tjmax = 125°C, $\theta_{j-c} = 150^\circ\text{C}/\text{W}$, $P_c = 0.0\text{W}$, $\Delta T_c = 47.5^\circ\text{C}$, $T_j = T_c + ((\theta_{j-c}) \times P_c) = 92.5^\circ\text{C}$ D.F. = 74.00%	$P_c(\text{max}) = 0.15\text{W}$ $T_c = 92.5^\circ\text{C}$
A1 FA13842N-D1-TE1 FUJI-ELEC.	Tjmax = 150°C, $\theta_{j-c} = 72^\circ\text{C}/\text{W}$ $P_d = 0.108\text{W}$, $\Delta T_c = 63.1^\circ\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times P_d) = 115.88^\circ\text{C}$ D.F. = 77.25%	$T_c = 108.1^\circ\text{C}$
A2 HA17431PA-TZ-E RENESAS	Tjmax = 150°C, $\theta_{j-c} = 100^\circ\text{C}/\text{W}$, $P_d = 7\text{mW}$, $\Delta T_c = 33.0^\circ\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times P_d) = 78.7^\circ\text{C}$ D.F. = 52.47%	$T_c = 78.0^\circ\text{C}$
PD1 264-7GVD/S530-E2 EVERLIGHT	IF = 6.4mA, $\Delta T_c = 32.0^\circ\text{C}$ Allowable IF(max)= 9mA(at Ta = 77.0°C) D.F. = 71.11%	$T_c = 77.0^\circ\text{C}$

(2) Component Derating List

Location No.	Vin = 230VAC	Load = 100%	Ta = 45°C
Q2 STP10NK80Z ST MICROELECTRONICS	Tchmax = 150°C, $\theta_{j-c} = 0.78^\circ\text{C}/\text{W}$, Pch = 4.4W, $\Delta T_c = 55.9^\circ\text{C}$, $T_c = 100.9^\circ\text{C}$ $T_c = T_c + ((\theta_{j-c}) \times Pch) = 104.33^\circ\text{C}$ D.F. = 69.55%	Pch(max) = 160W	
D8 STPS30H60CW ST MICROELECTRONICS	Tjmax = 175°C, $\theta_{j-c} = 0.8^\circ\text{C}/\text{W}$, Pd = 5.2W, $\Delta T_c = 61.6^\circ\text{C}$, $T_c = 106.6^\circ\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times Pd) = 110.76^\circ\text{C}$ D.F. = 63.29%		
D9 STPS30H60CW ST MICROELECTRONICS	Tjmax = 175°C, $\theta_{j-c} = 0.8^\circ\text{C}/\text{W}$, Pd = 5.2W, $\Delta T_c = 61.6^\circ\text{C}$, $T_c = 106.6^\circ\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times Pd) = 110.76^\circ\text{C}$ D.F. = 63.29%		
D1 RS405M RECTRON	Tjmax = 150°C, $\theta_{j-c} = 6.0^\circ\text{C}/\text{W}$, Pd = 1.79W, $\Delta T_c = 40.9^\circ\text{C}$, $T_c = 85.9^\circ\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times Pd) = 96.64^\circ\text{C}$ D.F. = 64.43%		
D2 HER208 RECTRON	Tjmax = 150°C, $\theta_{j-c} = 10^\circ\text{C}/\text{W}$, Pd = 0.3W, $\Delta T_c = 73.1^\circ\text{C}$, $T_c = 118.1^\circ\text{C}$ $T_j = T_a + ((\theta_{j-c}) \times Pd) = 121.1^\circ\text{C}$ D.F. = 80.73%		
D4 CRS04 TOSHIBA	Tjmax = 150°C, $\theta_{j-l} = 20^\circ\text{C}/\text{W}$, Pd = 2.5mW, $\Delta T_l = 48.7^\circ\text{C}$, $T_l = 93.7^\circ\text{C}$ $T_j = T_l + ((\theta_{j-l}) \times Pd) = 93.75^\circ\text{C}$ D.F. = 62.50%		
D5 CRS04 TOSHIBA	Tjmax = 150°C, $\theta_{j-l} = 20^\circ\text{C}/\text{W}$, Pd = 4.4mW, $\Delta T_l = 39.8^\circ\text{C}$, $T_l = 84.8^\circ\text{C}$ $T_j = T_l + ((\theta_{j-l}) \times Pd) = 84.89^\circ\text{C}$ D.F. = 56.59%		
D6 CRF02 TOSHIBA	Tjmax = 150°C, $\theta_{j-l} = 20^\circ\text{C}/\text{W}$, Pd = 47.8mW, $\Delta T_l = 73.6^\circ\text{C}$, $T_c = 118.6^\circ\text{C}$ $T_j = T_a + ((\theta_{j-l}) \times Pd) = 119.56^\circ\text{C}$ D.F. = 79.71%		
D7 CRH01 TOSHIBA	Tjmax = 150°C, $\theta_{j-l} = 20^\circ\text{C}/\text{W}$, Pd = 3.2mW, $\Delta T_l = 75.5^\circ\text{C}$, $T_l = 120.5^\circ\text{C}$ $T_j = T_l + ((\theta_{j-l}) \times Pd) = 120.56^\circ\text{C}$ D.F. = 80.37%		

Location No.	Vin = 230VAC Tjmax = 125°C, $\theta_{j-c} = 150^{\circ}\text{C}/\text{W}$, $P_c = 3.5\text{mW}$, $\Delta T_c = 38.4^{\circ}\text{C}$, $T_j = T_c + ((\theta_{j-c}) \times P_c) = 83.93^{\circ}\text{C}$ D.F. = 67.14%	Load = 100% $P_c(\text{max}) = 0.15\text{W}$ $T_c = 83.4^{\circ}\text{C}$
PC1 PS2561BL1-1-A(D) (TRANSISTOR) NEC	Tjmax = 125°C, $\theta_{j-c} = 150^{\circ}\text{C}/\text{W}$, $P_c = 2.34\text{mW}$, $\Delta T_c = 38.4^{\circ}\text{C}$, $T_j = T_c + ((\theta_{j-c}) \times P_c) = 83.75^{\circ}\text{C}$ D.F. = 67.00%	$P_c(\text{max}) = 0.15\text{W}$ $T_c = 83.4^{\circ}\text{C}$
PC2 PS2561BL1-1-A(D) (TRANSISTOR) NEC	Tjmax = 125°C, $\theta_{j-c} = 150^{\circ}\text{C}/\text{W}$, $P_c = 0.0\text{W}$, $\Delta T_c = 45.1^{\circ}\text{C}$, $T_j = T_c + ((\theta_{j-c}) \times P_c) = 90.1^{\circ}\text{C}$ D.F. = 72.08%	$P_c(\text{max}) = 0.15\text{W}$ $T_c = 90.1^{\circ}\text{C}$
PC2 PS2561BL1-1-A(D) (LED) NEC	Tjmax = 125°C, $\theta_{j-c} = 150^{\circ}\text{C}/\text{W}$, $P_c = 0.0\text{W}$, $\Delta T_c = 45.1^{\circ}\text{C}$, $T_j = T_c + ((\theta_{j-c}) \times P_c) = 90.1^{\circ}\text{C}$ D.F. = 72.08%	$P_c(\text{max}) = 0.15\text{W}$ $T_c = 90.1^{\circ}\text{C}$
A1 FA13842N-D1-TE1 FUJI-ELEC.	Tjmax = 150°C, $\theta_{j-c} = 72^{\circ}\text{C}/\text{W}$ $P_d = 0.118\text{W}$, $\Delta T_c = 59.6^{\circ}\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times P_d) = 113.1^{\circ}\text{C}$ D.F. = 75.40%	$T_c = 104.6^{\circ}\text{C}$
A2 HA17431PA-TZ-E RENESAS	Tjmax = 150°C, $\theta_{j-c} = 100^{\circ}\text{C}/\text{W}$, $P_d = 7\text{mW}$, $\Delta T_c = 32.8^{\circ}\text{C}$ $T_j = T_c + ((\theta_{j-c}) \times P_d) = 78.5^{\circ}\text{C}$ D.F. = 52.33%	$T_c = 77.8^{\circ}\text{C}$
PD1 264-7GVD/S530-E2 EVERLIGHT	IF = 6.4mA, $\Delta T_c = 30.8^{\circ}\text{C}$ Allowable IF(max)= 9.5mA(at Ta = 75.8°C) D.F. = 67.37%	$T_c = 75.8^{\circ}\text{C}$

3. Main components temperature rise ΔT list

MODEL : LS100-5

Condition:

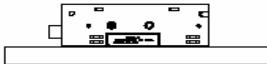
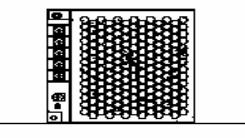
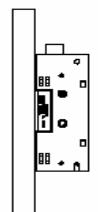
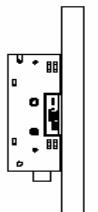
Standard Mounting (Mounting Method (A))	(A)			
	Mounting A	Mounting B	Mounting C	Mounting D
Input Voltage (VAC)		115		
Output Voltage (VDC)		5		
Output Current (A)		16		

Output Derating $T_a = 45^\circ\text{C}$		ΔT Temperature rise ($^\circ\text{C}$)			
Location No	Parts Name	$Io=100\%$	$Io=100\%$	$Io=100\%$	$Io=100\%$
F1	FUSE	27.2	32.9	45.3	25.3
L1	BALUN COIL	43.0	48.1	56.7	38.3
L2	CHOKE COIL	62.7	57.1	66.2	52.2
L3	CHOKE COIL	57.7	62.4	65.6	50.2
T1	TRANS. PULSE	67.2	59.2	57.1	62.6
Q2	MOSFET	59.2	57.4	53.6	62.6
D1	BRIDGE DIODE	61.0	65.6	63.6	64.0
D8	F.R. DIODE	65.2	61.1	59.3	61.0
D9	F.R. DIODE	65.2	58.8	58.1	56.5
A1	CHIP IC	63.1	55.8	51.8	65.0
A2	SHUNT REGULATOR	33.0	41.2	57.0	26.9
PC1	PHOTOCOUPLER	45.4	42.2	38.1	43.4
PC2	PHOTOCOUPLER	47.5	42.6	40.7	45.1
PD1	LED	32.0	35.1	52.7	27.2
C7	CAP. FILM	45.8	55.1	52.8	55.8
C9	CAP. ELECT.	41.6	44.8	34.8	50.0
C10	CAP. ELECT.	42.7	48.0	40.0	48.1
C24	CAP. ELECT.	54.1	45.7	41.8	58.6
C28	CAP. ELECT.	57.1	51.2	52.9	48.2
C29	CAP. ELECT.	54.2	51.4	53.3	46.1
C30	CAP. ELECT.	51.9	51.8	54.4	44.0
C31	CAP. ELECT.	52.8	47.4	50.0	44.3
C32	CAP. ELECT.	50.4	47.9	51.3	43.1
C33	CAP. ELECT.	44.4	43.4	49.5	37.0
C34	CAP. ELECT.	41.8	45.9	51.7	36.0

3. Main components temperature rise ΔT list

MODEL : LS100-5

Condition:

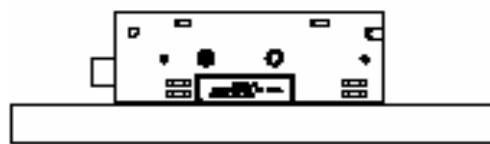
	(A)			
	Mounting A	Mounting B	Mounting C	Mounting D
Standard Mounting (Mounting Method (A))				
Input Voltage (VAC)		230		
Output Voltage (VDC)		5		
Output Current (A)		16		

Output Derating $T_a = 45^\circ C$		ΔT Temperature rise ($^\circ C$)			
Location No	Parts Name	Mounting (A)	Mounting (B)	Mounting (C)	Mounting (D)
F1	FUSE	22.1	28.1	33.6	20.3
L1	BALUN COIL	27.6	34.6	38.2	23.9
L2	CHOKE COIL	38.9	39.8	44.1	31.8
L3	CHOKE COIL	57.4	61.4	64.9	49.1
T1	TRANS. PULSE	65.7	56.7	56.2	60.7
Q2	MOSFET	55.9	54.3	50.1	57.7
D1	BRIDGE DIODE	40.9	49.7	46.0	42.7
D8	F.R. DIODE	61.6	58.8	56.7	58.0
D9	F.R. DIODE	61.6	57.2	55.9	54.2
A1	CHIP IC	59.6	55.6	51.7	64.4
A2	SHUNT REGULATOR	32.8	40.1	56.4	26.3
PC1	PHOTOCOUPLER	38.4	40.5	37.3	41.1
PC2	PHOTOCOUPLER	45.1	41.5	39.3	42.9
PD1	LED	30.8	34.9	51.6	26.7
C7	CAP. FILM	33.3	44.4	39.8	37.8
C9	CAP. ELECT.	38.1	42.3	31.6	44.1
C10	CAP. ELECT.	36.7	44.6	34.9	38.7
C24	CAP. ELECT.	52.7	45.4	40.6	56.9
C28	CAP. ELECT.	53.8	49.5	50.5	45.5
C29	CAP. ELECT.	51.5	50.0	51.0	43.7
C30	CAP. ELECT.	50.3	51.1	52.4	42.6
C31	CAP. ELECT.	48.4	45.8	47.4	41.4
C32	CAP. ELECT.	47.0	46.3	48.4	40.4
C33	CAP. ELECT.	42.3	42.2	46.5	35.1
C34	CAP. ELECT.	40.6	45.3	49.2	34.8

4. Electrolytic capacitor lifetime

MODEL : LS100-5

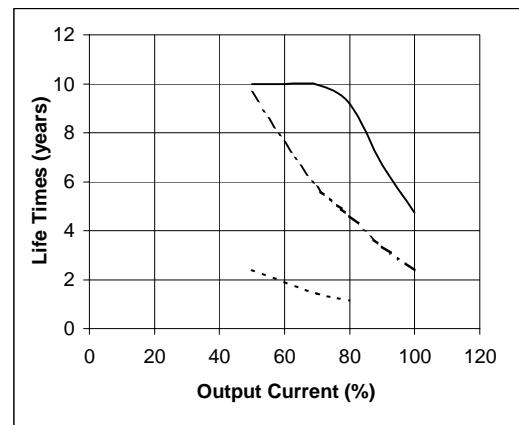
Mounting A



Ta = 40°C
= 50°C
= 70°C

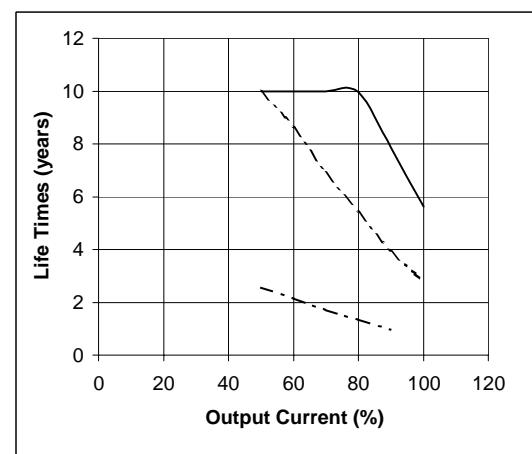
Vin = 115VAC

Load (%)	Life Time (years)		
	Ta = 40°C	Ta = 50°C	Ta = 70°C
50	10.0	9.6	2.4
60	10.0	7.6	1.9
70	10.0	5.8	1.4
80	9.2	4.6	1.1
90	6.7	3.3	—
100	4.7	2.4	—



Vin = 230VAC

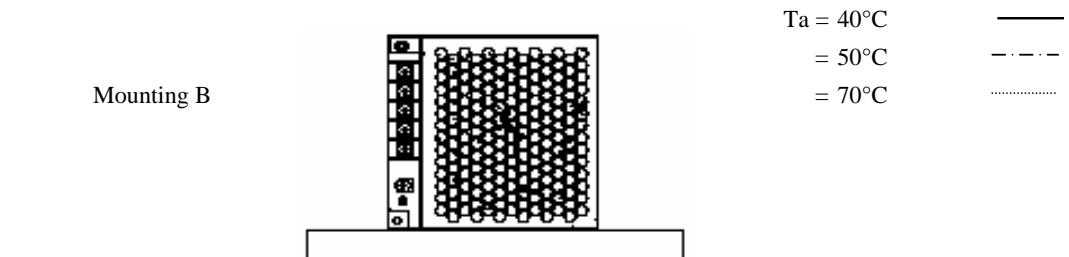
Load (%)	Life Time (years)		
	Ta = 40°C	Ta = 50°C	Ta = 70°C
50	10.0	10.0	2.6
60	10.0	8.6	2.2
70	10.0	6.9	1.7
80	10.0	5.4	1.4
90	7.8	3.9	1.0
100	5.6	2.8	—



Note : E-cap life calculation is based on 8hrs/day operation.

4. Electrolytic capacitor lifetime

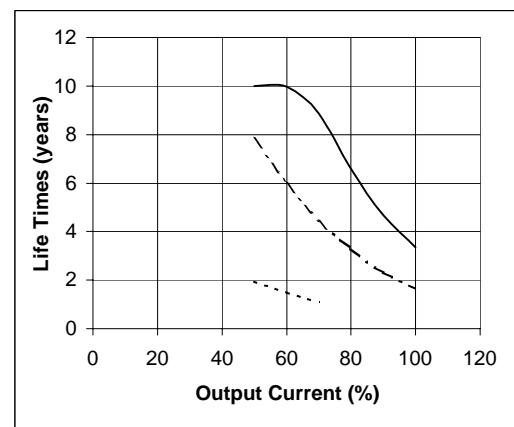
MODEL : LS100-5



Ta = 40°C
= 50°C
= 70°C

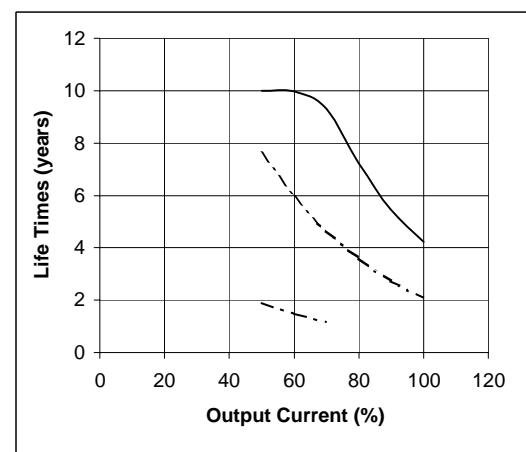
Vin = 115VAC

Load (%)	Life Time (years)		
	Ta = 40°C	Ta = 50°C	Ta = 70°C
50	10.0	7.8	2.0
60	10.0	6.0	1.5
70	8.9	4.4	1.1
80	6.6	3.3	—
90	4.7	2.3	—
100	3.3	1.7	—



Vin = 230VAC

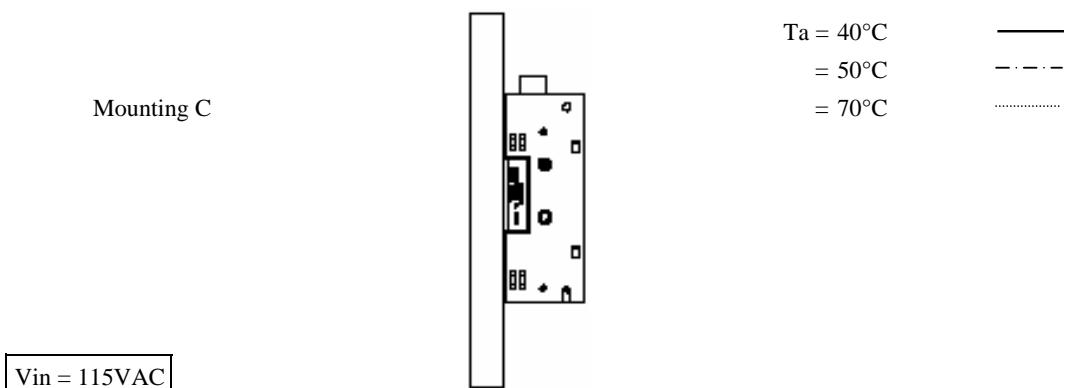
Load (%)	Life Time (years)		
	Ta = 40°C	Ta = 50°C	Ta = 70°C
50	10.0	7.6	1.9
60	10.0	6.0	1.5
70	9.3	4.7	1.2
80	7.2	3.6	—
90	5.5	2.7	—
100	4.2	2.1	—



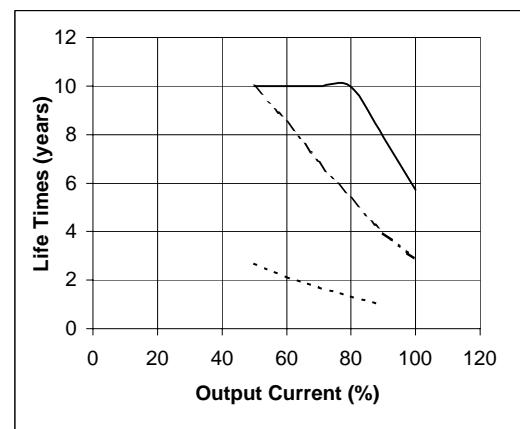
Note : E-cap life calculation is based on 8hrs/day operation.

4. Electrolytic capacitor lifetime

MODEL : LS100-5

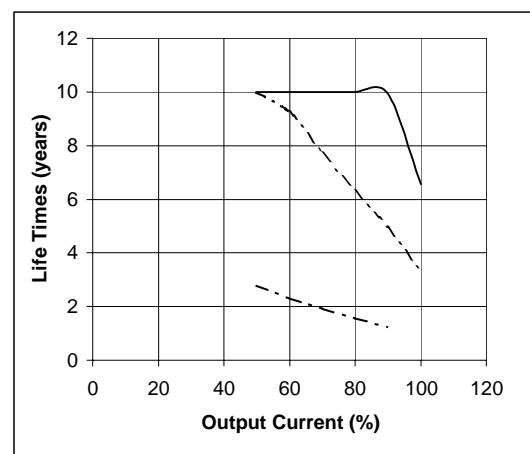


Load (%)	Life Time (years)		
	Ta = 40°C	Ta = 50°C	Ta = 70°C
50	10.0	10.0	2.7
60	10.0	8.5	2.1
70	10.0	6.9	1.7
80	10.0	5.4	1.3
90	7.9	3.9	1.0
100	5.7	2.9	—



Vin = 230VAC

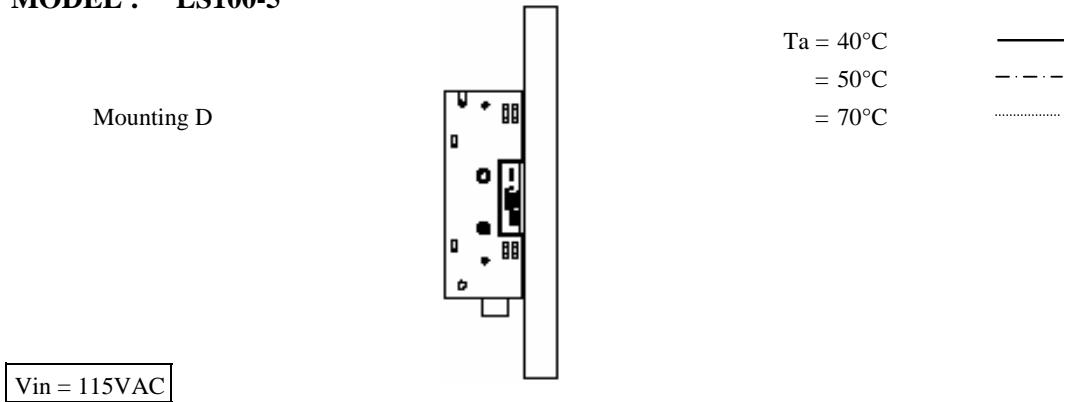
Load (%)	Life Time (years)		
	Ta = 40°C	Ta = 50°C	Ta = 70°C
50	10.0	10.0	2.8
60	10.0	9.2	2.3
70	10.0	7.7	1.9
80	10.0	6.3	1.6
90	9.9	5.0	1.2
100	6.6	3.3	—



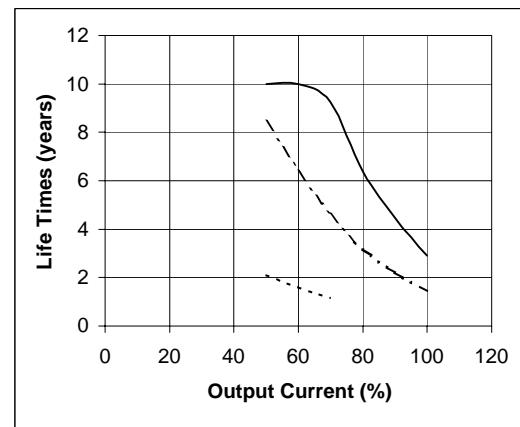
Note : E-cap life calculation is based on 8hrs/day operation.

4. Electrolytic capacitor lifetime

MODEL : LS100-5

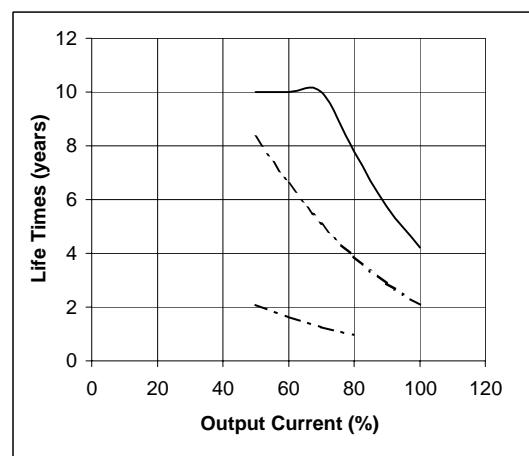


Load (%)	Life Time (years)		
	Ta = 40°C	Ta = 50°C	Ta = 70°C
50	10.0	8.5	2.1
60	10.0	6.4	1.6
70	9.2	4.6	1.2
80	6.4	3.2	—
90	4.5	2.2	—
100	2.9	1.5	—



Vin = 230VAC

Load (%)	Life Time (years)		
	Ta = 40°C	Ta = 50°C	Ta = 70°C
50	10.0	8.3	2.1
60	10.0	6.6	1.6
70	10.0	5.1	1.3
80	7.8	3.9	1.0
90	5.7	2.9	—
100	4.2	2.1	—



Note : E-cap life calculation is based on 8hrs/day operation.

5. Vibration Test

MODEL : LS100-5

(1) Vibration Test Class

Frequency Variable Endurance Test

(2) Equipment Used

Controller	:	F-400-BM-E47 (EMIC CORP.)
Vibrator	:	905-FN (EMIC CORP.)
Serial no.	:	22965

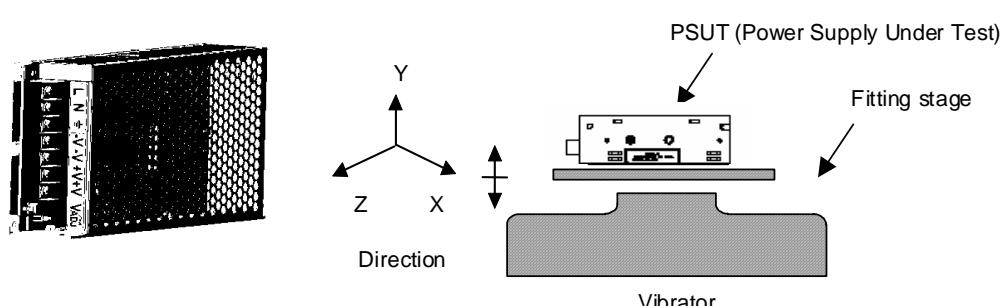
(3) The Number Of D.U.T. (Device Under Test)

1 Unit

(4) Test Conditions

Sweep Frequency	:	10 - 55Hz	Direction	:	X, Y, Z
Sweep Time	:	1 minute	Test Time	:	1 hour each axis
Acceleration	:	2G	Non-operation		
Mounting	:	A and B			

(5) Test Method



Fix the PSUT on the universal plate via two M3 tapped holes on the chassis of the power supply.
Standard mounting position as per test specification.

(6) Test results - OK

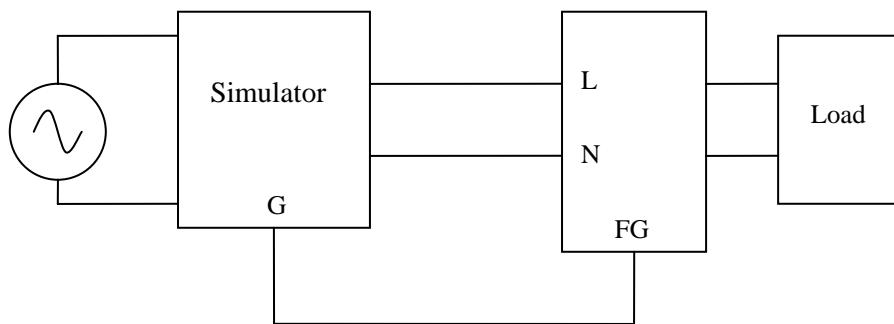
Test Conditions :	Vin	= 230 Vac	Load Condition :
	Ambient Temp.	= +25 °C	Full Load

Check Item		Output Voltage (V)	PSUT State
Before Test		V _{o1}	
5.003			
After test	X	5.003	OK
	Y	5.003	OK
	Z	5.003	OK

6. Noise simulate test

MODEL : LS100-5

(1) Test circuit and equipment



Simulator : INS-400L Noise Laboratory Co.,LTD

(2) Test conditions

- | | | | |
|-----------------------|----------------|------------------|-----------------|
| • Input voltage | : 115, 230VAC | • Noise level | : 0V~2.4kV |
| • Output voltage | : Rated | • Phase shift | : 0° ~ 360° |
| • Output current | : 0%, 100% | • Polarity | : +, - |
| • Ambient temperature | : 25°C | • Mode | : Normal Common |
| • Pulse Width | : 0ns ~ 1000ns | • Trigger select | : Line |

(3) Acceptable conditions

1. Not to be broken.
2. No output shutdown.
3. No other out of order.

(4) Test result O K

7. Abnormal test

MODEL : LS100-5

(1) Test Condition

Input Voltage : 230VAC Output Current : 100% Ta : 25°C, 70% RH

(2) Test Results

(Da: Damaged)

No.	Test Position		Test Mode		Test Results												NOTE
	LOCATION	TEST POINT	S H O R T	O P E N	1	2	3	4	5	6	7	8	9	10	11	12	
					F I M O R S E K T	S M U O R L E T	B U M S L H A O G B L O W	S E D M A G E O E B L O W	R E A M A G E O E B L O W	D A C M A G E U E P .C V P .	F U C S P .	O .C V P .	O O P U T T P H A H A N U G U T	N O O C C H A H A N G E	O T H E R		
1	D1	(+) - (-)	•								•	•		•			Da : F1
2	D2		•											•			Hiccup
3	D3		•											•	•		Latch
4	D4		•											•	•		Hiccup
5	D5		•											•			
6	D6		•											•			
7	D7		•								•	•		•			Da : F1,Q2,Z4,D2
8	D8/D9		•											•			No Damage
			•											•			Da : R43, A1
9	Q1	3 - 4	•											•	•		Latch
			•											•			
		1 - 6	•											•	•		Latch
			•											•			
		3 - 5	•											•	•		Latch
			•											•			
10	Q2	6 - 2	•											•			Latch
			•											•			
		G - S	•											•			Da : R43
		D - G	•											•	•		Da : R43, Z1, Z2, F1
11	Q3	D - S	•											•	•		Da : F1, R43, Z1
		C - E	•														
		B - E	•													•	Hiccup
12	C9/C10	C - B	•														
		(+)Bulk - (-)Bulk	•								•	•		•			Da : F1
			•								•	•		•			Da : F1, Z2
13	C13		•													•	

7. Abnormal test

MODEL : LS100-5

(1) Test Condition

Input Voltage : 230VAC Output Current : 100% Ta : 25°C, 70% RH

(2) Test Results

(Da: Damaged)

No.	Test Position		Test Mode		Test Results												NOTE
	LOCATION	TEST POINT	S H O R T	O P E R E N	1	2	3	4	5	6	7	8	9	10	11	12	
					F I M O R S E K T	S M U O R L E T	B U M S L H A O G E B C P A O G W	S E D M L H A G E B P P U T P U G E	R E A M D A G E L B C P U T A H U N C H A G E								
14	C17/R39	C17/R39	•											•			Da : F1,Q2,Z1
		C17	•									•	•				
		R39	•														
15	C18		•												•		Hissing sound
16	C21		•								•	•		•			Da : F1,Q2,Z1,Z2
17	C38/C39		•												•		Hissing sound
18	PC1	1 - 2	•											•	•	•	Latch
		3 - 4	•												•		Latch
		1 - 2	•											•	•	•	Latch
		3 - 4	•											•	•	•	Latch
19	PC2	3 - 4	•												•	•	Latch
			•												•		
		1 - 2	•												•		
			•												•		
		Vcc - GND	•												•		
20	A1	Vref - GND	•												•		
		Isense - GND	•												•		
		RtCt - GND	•												•		
		FB - GND	•												•		
		Comp - GND	•												•		
		Out - GND	•												•		
		A - K	•												•		Vo = 1.34
21	A2	R - K	•												•		Vo = 3.78
		R - A	•												•	•	Latch
		Np	•												•	•	Da : F1,Q1,Z3,Z4
22	T1	Nbias	•									•	•		•		Da : F1,Q1,D2,Z4
		Ns	•									•	•		•		Da : F1,Q1
			•												•		No Led Light
23	PD1		•			•									•		No Led Light

7. Abnormal test

MODEL : LS100-5

(1) Test Condition

Input Voltage : 230VAC Output Current : 100% Ta : 25°C, 70% RH

(2) Test Results

(Da: Damaged)

No.	Test Position		Test Mode		Test Results												NOTE
	LOCATION	TEST POINT	S H O R T	O P E R E N	1	2	3	4	5	6	7	8	9	10	11	12	
					F I M O R K S T	S M U O R E L	B U M S L	S E D L	R E A M	D A M A	F U S C	O .C V	O P	O P	N O O	N O O	O T H E R
24	Z1		•											•			
25	Z2		•													•	Hissing sound
26	Z4		•											•	•		Latch
27	R9/R10/C11	R9/R10/C11	•												•		
	R9 & R10	R9 & R10	•												•		
	C11	C11	•											•	•		
28	R18		•													•	
29	R26		•												•		
30	R32~R36		•												•		
31	R42		•									•	•		•		Da : F1,Q2,Z2
32	R43		•													•	Hissing sound
33	R55		•											•	•	•	Latch
34	R56		•													•	Hissing sound
35	VR1		•													•	Vo = 5.73
					•											•	Vo = 3.25

8. Thermal shock test

MODEL : LS100

(1) Equipment used

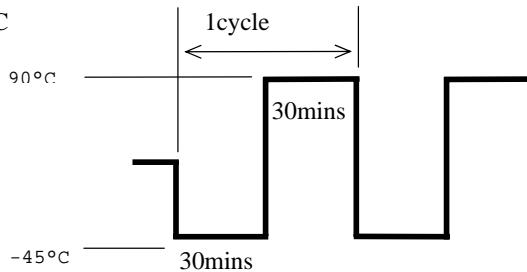
THERMAL SHOCK CHAMBER TSA-101S-W (ESPEC CORP.)

(2) The number of D.U.T.(Device Under Test)

1 unit

(3) Test Conditions

- Ambient temperature : -45°C ↔ 90°C
- Test time : 30 mins each temp.
- Test cycle : 100 cycles
- Not operating



(4) Test Method

Before testing, check if there is no abnormal output, then put the D.U.T. in testing chamber, and test it according to the above cycle. 100 cycles later, leave it for 1 hour at the room temperature, then check if there is no abnormal output.

(5) Test Results **OK**

Vin : 230VAC			3.3V			
Io : 100%			From		To	
Ripple&Spike noise			mV	13.52		16
Line regulation	Full load	mV	14		3	
Load regulation	Vin:115V	mV	39		10	
Efficiency	Pin	W	87.93		87.85	
	Vout	V	3.273	74.44%	3.315	75.47%
	Iout	A	20		20	
Solder condition • etc.			—		OK	